



ULQ2001A - ULQ2003A ULQ2002A - ULQ2004A

SEVEN DARLINGTON ARRAYS

- SEVEN DARLINGTONS PER PACKAGE
- **EXTENDED TEMPERATURE RANGE**
(-40 to 105°C)
- OUTPUT CURRENT 500 mA PER DRIVER
(600 mA PEAK)
- OUTPUT VOLTAGE 50 V
- INTEGRAL SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL/CMOS/PMOS/DTL COMPATIBLE INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT

DESCRIPTION

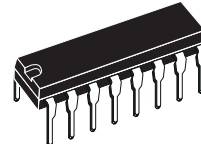
The ULQ2001A, ULQ2002A, ULQ2003 and ULQ2004A are high voltage, high current darlington arrays each containing seven open collector darlington pairs with common emitters. Each channel is rated at 500 mA and can withstand peak currents of 600 mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

The four versions interface to all common logic families :

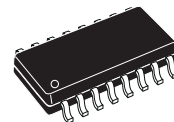
ULQ2001A	General Purpose, DTL, TTL, PMOS, CMOS
ULQ2002A	14-25V PMOS
ULQ2003A	5V TTL, CMOS
ULQ2004A	6-15V CMOS, PMOS

These versatile devices are useful for driving a wide range of loads including solenoids, relays DC motors, LED displays filament lamps, thermal print-heads and high power buffers.

The ULQ2001A/2002A/2003A and 2004A are supplied in 16 pin plastic DIP packages with a copper leadframe to reduce thermal resistance. They are available also in small outline package (SO-16) as ULQ2001D1/2002D1/2003D1/2004D1.



DIP16

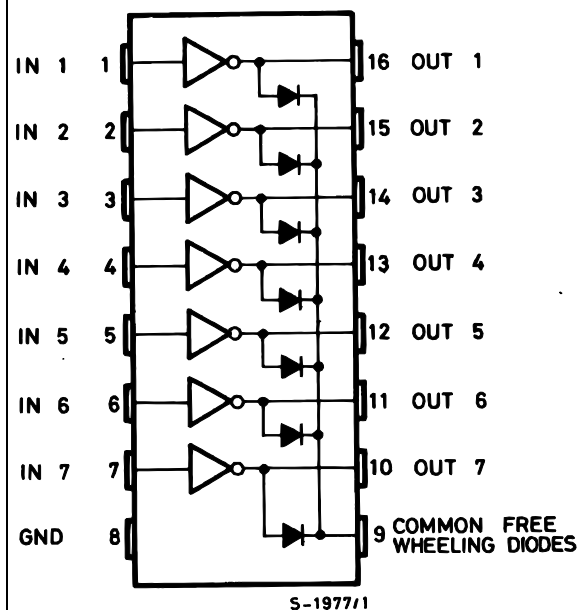


SO16

ORDERING NUMBERS:

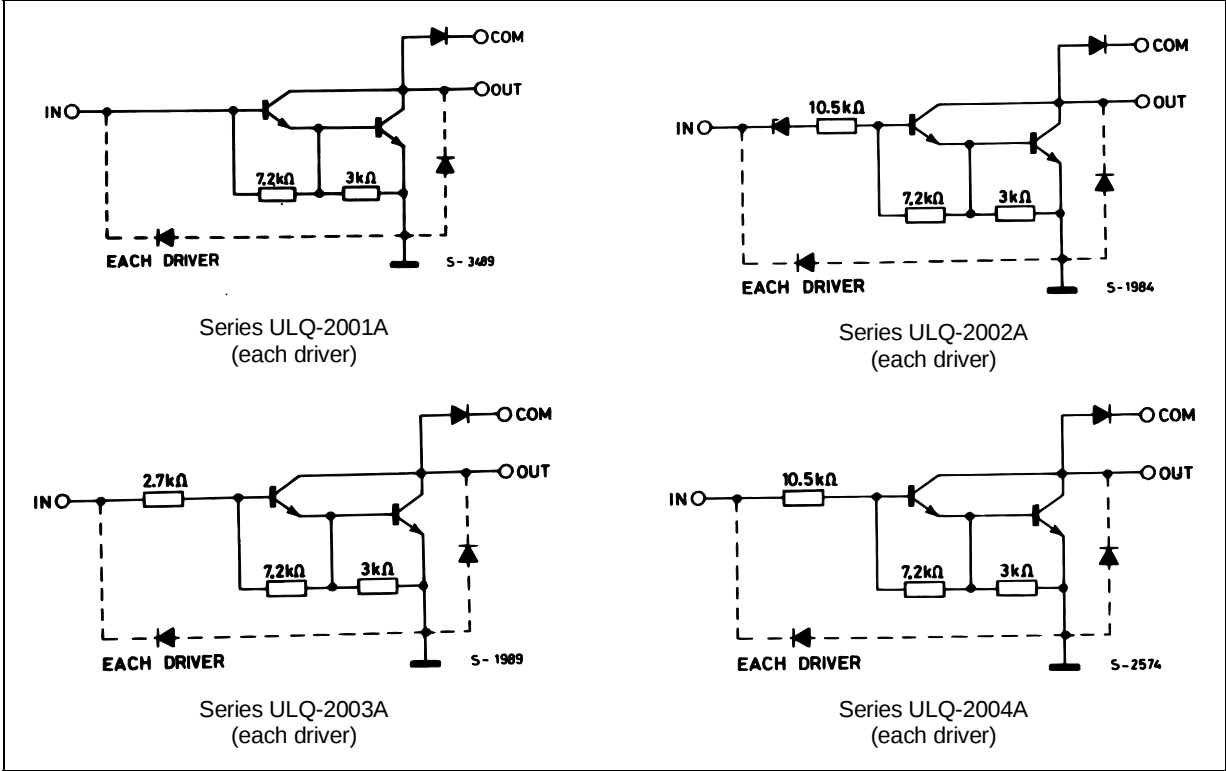
ULQ2001A/2A/3A/4A (DIP16)
ULQ2001D1/2D1/3D1/4D1 (SO16)

PIN CONNECTION



ULQ2001A - ULQ2002A - ULQ2003A - ULQ2004A

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_o	Output Voltage	50	V
V_{in}	Input Voltage (for ULQ2002A/D1 - 2003A/D1 - 2004A/D1)	30	V
I_c	Continuous Collector Current	500	mA
I_b	Continuous Base Current	25	mA
T_{amb}	Operating Ambient Temperature Range	-40 to 105	°C
T_{stg}	Storage Temperature Range	-55 to 150	°C
T_j	Junction Temperature	150	°C

THERMAL DATA

Symbol	Parameter	DIP16	SO16	Unit
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	70	120	°C/W

ULQ2001A - ULQ2002A - ULQ2003A - ULQ2004A

ELECTRICAL CHARACTERISTICS (T_J = -40 to 105°C for DIP16 unless otherwise specified) (T_J = 25 to 105°C for SO16 unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
I _{CEX}	Output Leakage Current	V _{CE} = 50V T _J = 105°C, V _{CE} = 50V T _J = 105°C for ULQ2002A V _{CE} = 50V, V _i = 6V for ULQ2004A V _{CE} = 50V, V _i = 1V			50 100 500 500	μA μA μA μA	1a 1a 1b 1b
V _{CE(sat)}	Collector-emitter Saturation Voltage	I _C = 100mA, I _B = 250μA I _C = 200mA, I _B = 350μA I _C = 350mA, I _B = 500μA		0.9 1.1 1.3	1.1 1.3 1.6	V V V	2 2 2
I _{i(on)}	Input Current	for ULQ2002A V _i = 17V for ULQ2003A V _i = 3.85V for ULQ2004A V _i = 5V V _i = 12V		0.82 0.93 0.35 1	1.25 1.35 0.5 1.45	mA mA mA mA	3 3 3 3
I _{i(off)}	Input Current	T _J = 105°C, I _C = 500μA	50	65		μA	4
V _{i(on)}	Input Voltage	for ULQ2002A V _{CE} = 2V, I _C = 300mA for ULQ2003A V _{CE} = 2V, I _C = 200mA V _{CE} = 2V, I _C = 250mA V _{CE} = 2V, I _C = 300mA for ULQ2004A V _{CE} = 2V, I _C = 125mA V _{CE} = 2V, I _C = 200mA V _{CE} = 2V, I _C = 275mA V _{CE} = 2V, I _C = 350mA			13 2.4 2.7 3 5 6 7 8	V V V V V V V V	5 5 5 5 5 5 5 5
h _{FE}	DC Forward Current Gain	for ULQ2001A V _{CE} = 2V, I _C = 350mA	1000			—	2
C _i	Input Capacitance			15	25 (*)	pF	—
t _{PLH}	Turn-on Delay Time	0.5 V _i to 0.5 V _o		0.25	1 (*)	μs	—
t _{PHL}	Turn-off Delay Time	0.5 V _i to 0.5 V _o		0.25	1 (*)	μs	—
I _R	Clamp Diode Leakage Current	V _R = 50V T _J = 105°C, V _R = 50V			50 100	μA μA	6 6
V _F	Clamp Diode Forward Voltage	I _F = 350mA		1.7	2	V	7

(*) Guaranteed by design

TEST CIRCUITS

Figure 1a.

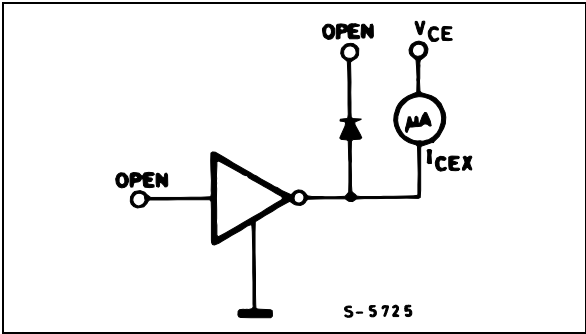


Figure 1b.

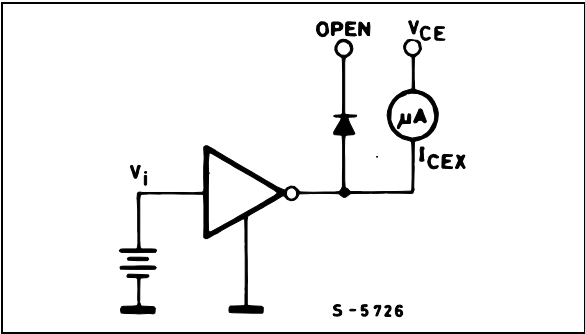


Figure 2.

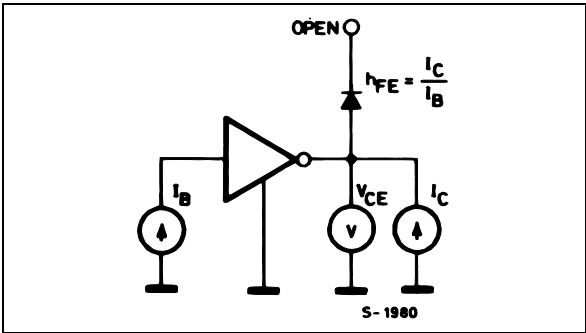


Figure 3.

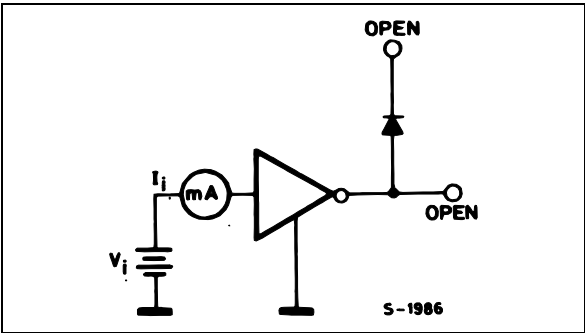


Figure 4.

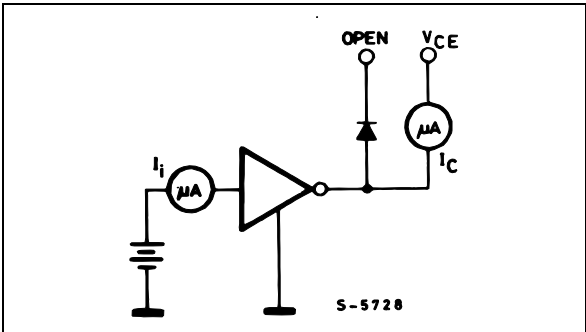


Figure 5.

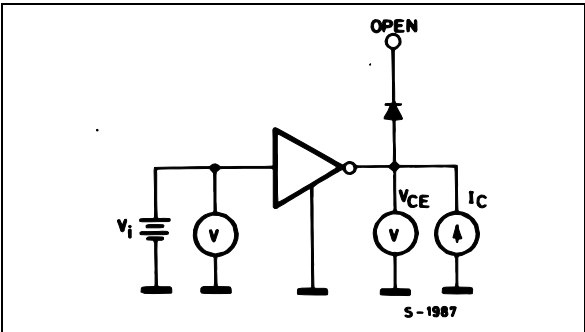


Figure 6.

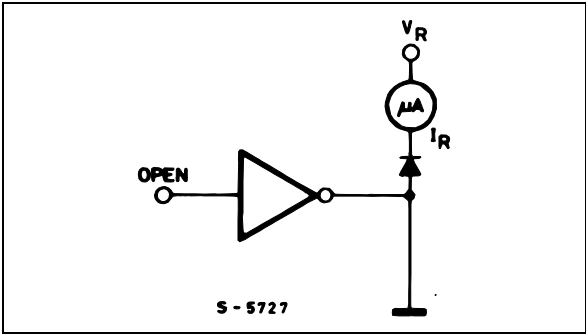
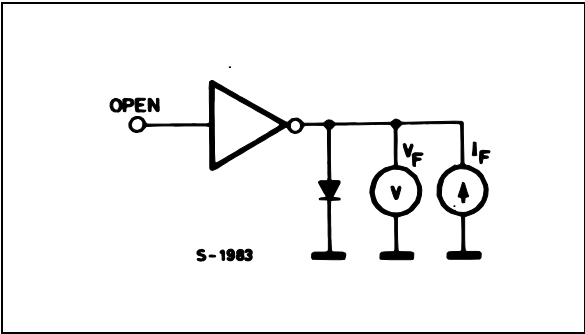
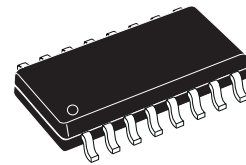


Figure 7.



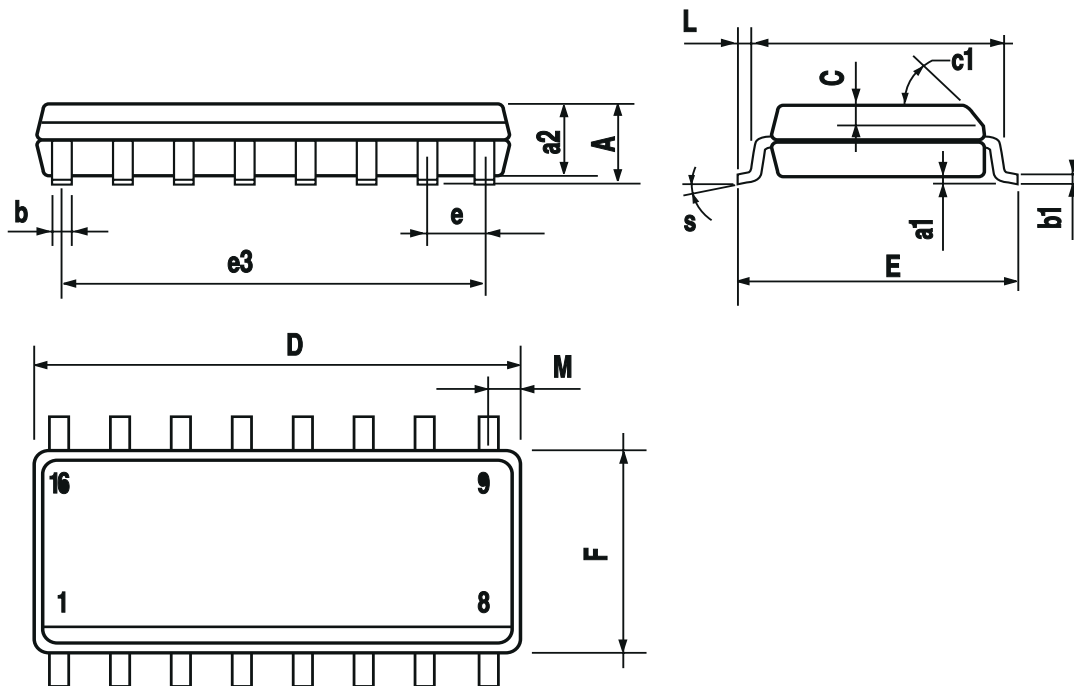
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D (1)	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F (1)	3.8		4	0.150		0.157
G	4.6		5.3	0.181		0.209
L	0.4		1.27	0.016		0.050
M			0.62			0.024
S	8°(max.)					

OUTLINE AND MECHANICAL DATA



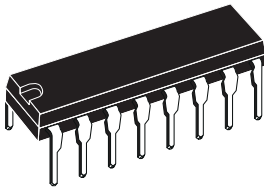
SO16 Narrow

(1) D and F do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm (.006inch).

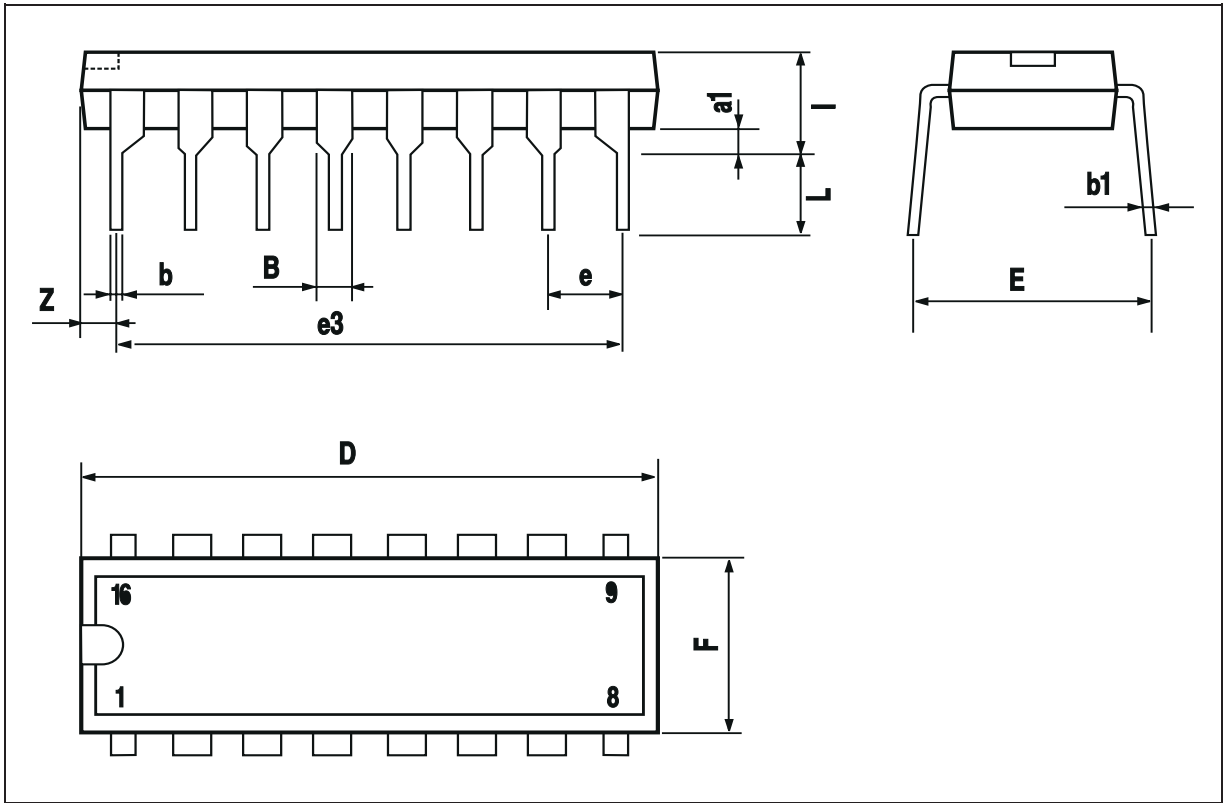


DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

OUTLINE AND
MECHANICAL DATA



DIP16



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